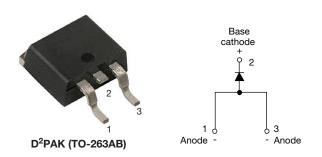


RoHS

COMPLIANT HALOGEN

FREE

Surface Mount Fast Soft Recovery Rectifier Diode, 10 A



PRIMARY CHARACTERISTICS						
I _{F(AV)}	10 A					
V_{R}	1200 V					
V _F at I _F	1.33 V					
I _{FSM}	155 A					
t _{rr}	80 ns					
T_J max.	150 °C					
Package	D ² PAK (TO-263AB)					
Circuit configuration	Single					
Snap factor	0.6					

FEATURES

- Meets MSL level 1, per J-STD-020, LF maximum peak of 245 °C
- Glass passivated pellet chip junction
- AEC-Q101 qualified
- Meets JESD 201 class 1A whisker test
- Flexible solution for reliable AC power rectification
- High surge, low V_F rugged blocking diode for DC charging stations
- Material categorization: for definitions of compliance please see <u>www.vishay.com/doc?99912</u>

APPLICATIONS

- · Input rectification
- · On-board and off-board EV / HEV battery chargers

DESCRIPTION

The VS-10ETF12SLHM3 fast soft recovery rectifier series has been optimized for combined short reverse recovery time and low forward voltage drop.

The glass passivation ensures stable reliable operation in the most severe temperature and power cycling conditions.

MAJOR RATINGS AND CHARACTERISTICS								
SYMBOL	CHARACTERISTICS	VALUES	UNITS					
I _{F(AV)}	Sinusoidal waveform	10	Α					
V _{RRM}		1200	V					
I _{FSM}		155	Α					
V _F	10 A, T _J = 25 °C	1.33	V					
t _{rr}	1 A, 100 A/µs	80	ns					
TJ	Range	-40 to +150	°C					

VOLTAGE RATINGS									
PART NUMBER	V _{RRM} , MAXIMUM PEAK REVERSE VOLTAGE V	V _{RSM} , MAXIMUM NON-REPETITIVE PEAK REVERSE VOLTAGE V	I _{RRM} AT 150 °C mA						
VS-10ETF12SLHM3	1200	1300	4						

ABSOLUTE MAXIMUM RATINGS								
PARAMETER	SYMBOL	TEST CONDITIONS	VALUES	UNITS				
Maximum average forward current	I _{F(AV)}	T _C = 125 °C, 180° conduction half sine wave	10					
Maximum peak one cycle non-repetitive	I _{FSM}	10 ms sine pulse, rated V _{RRM} applied	130	Α				
surge current		10 ms sine pulse, no voltage reapplied	155					
Maximum I ² t for fusing	l ² t	10 ms sine pulse, rated V _{RRM} applied	85	A ² s				
Maximum I-t for fusing	1-1	10 ms sine pulse, no voltage reapplied	120	A-5				
Maximum I ² √t for fusing	I ² √t	t = 0.1 ms to 10 ms, no voltage reapplied	1200	A²√s				



ELECTRICAL SPECIFICATIONS								
PARAMETER	SYMBOL	TEST CO	VALUES	UNITS				
Maximum forward voltage drop	V_{FM}	10 A, T _J = 25 °C	1.33	V				
Forward slope resistance	r _t	T _{.1} = 150 °C	22.9	mΩ				
Threshold voltage	V _{F(TO)}	1j = 130 C	0.96	V				
Maximum rayaraa laakaga aurrant	1	T _J = 25 °C	V - rotod V	0.1	mA			
Maximum reverse leakage current	IRM	T _J = 150 °C	V_R = rated V_{RRM}	4	IIIA			

RECOVERY CHARACTERISTICS								
PARAMETER	SYMBOL	TEST CONDITIONS	VALUES	UNITS	+			
Reverse recovery time	t _{rr}	I- at 10 A	310	ns	I _{FM}			
Reverse recovery current	I _{rr}	- I _F at 10 A _{pk} 25 A/µs	4.7	Α	, t _m			
Reverse recovery charge	Q _{rr}	25 °C	1.05	μC	dir/ dt Q _{rr}			
Typical snap factor	S		0.6		I _{RM(REC)}			

THERMAL - MECHANICAL SPECIFICATIONS							
PARAMETER	SYMBOL	TEST CONDITIONS	VALUES	UNITS			
Maximum junction and storage temperature range	T _J , T _{Stg}		-40 to +150	°C			
Maximum thermal resistance, junction to case	R _{thJC}	DC operation	1.5	°C/W			
Maximum thermal resistance, junction to ambient (PCB mount)	R _{thJA} (1)		62				
Approximate weight			2	g			
Approximate weight			0.07	oz.			
Marking device		Case style D ² PAK (TO-263AB)	10ETF	12SH			

Note

 $^{^{(1)}}$ When mounted on 1" square (650 mm²) PCB of FR-4 or G-10 material 4 oz. (140 μ m) copper 40 °C/W

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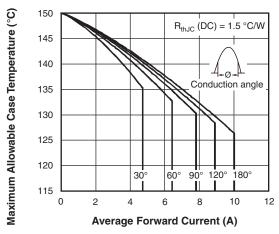


Fig. 1 - Current Rating Characteristics

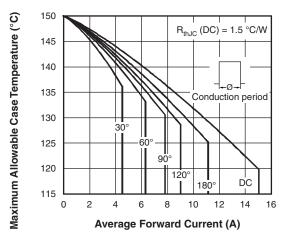


Fig. 2 - Current Rating Characteristics

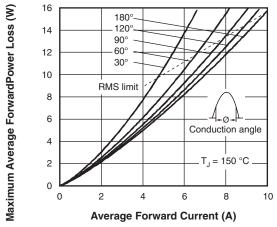


Fig. 3 - Forward Power Loss Characteristics

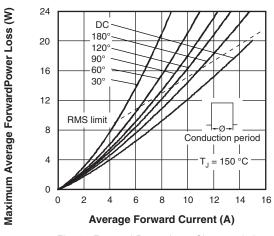


Fig. 4 - Forward Power Loss Characteristics

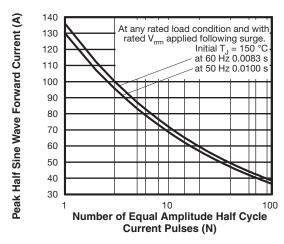


Fig. 5 - Maximum Non-Repetitive Surge Current

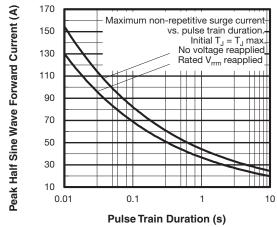


Fig. 6 - Maximum Non-Repetitive Surge Current

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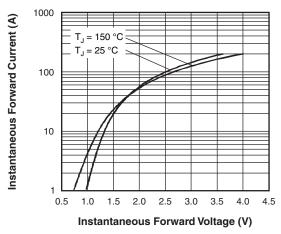


Fig. 7 - Forward Voltage Drop Characteristics

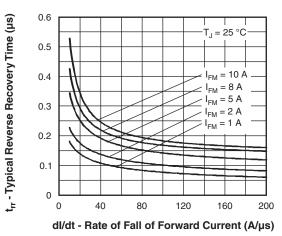


Fig. 8 - Recovery Time Characteristics, $T_J = 25$ °C

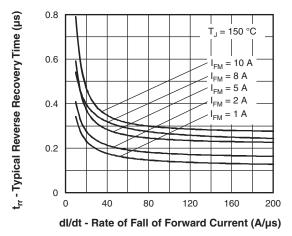


Fig. 9 - Recovery Time Characteristics, $T_J = 150 \, ^{\circ}\text{C}$

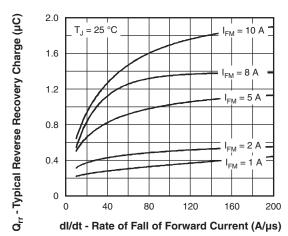


Fig. 10 - Recovery Charge Characteristics, $T_J = 25$ °C

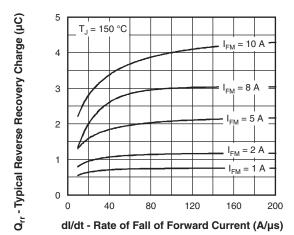


Fig. 11 - Recovery Charge Characteristics, T_J = 150 °C

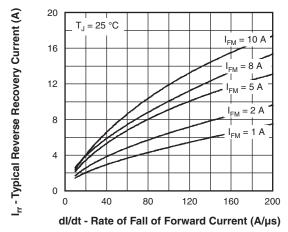


Fig. 12 - Recovery Current Characteristics, $T_J = 25$ °C

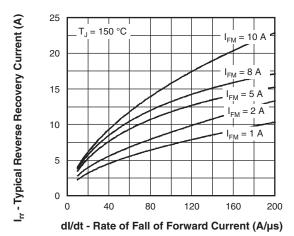


Fig. 13 - Recovery Current Characteristics, T_J = 150 °C

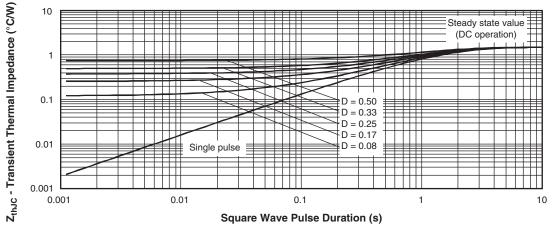
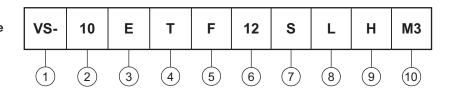


Fig. 14 - Thermal Impedance Z_{thJC} Characteristics



ORDERING INFORMATION TABLE

Device code



1 - Vishay Semiconductors product

2 - Current rating (10 = 10 A)

Circuit configuration:

E = single

4 - Package:

 $T = D^2PAK (TO-263AB)$

5 - Type of silicon:

F = fast soft recovery rectifier

6 - Voltage code x 100 = V_{RRM} ----- 12 = 1200 V

7 - S = surface mountable

 L = tape and reel (left oriented), for different orientation, contact factory

9 - H = AEC-Q101 qualified

| 10 - Environmental digit:

M3 = halogen-free, RoHS-compliant, and terminations lead (Pb)-free

ORDERING INFORMATION (Example)								
PREFERRED P/N	QUANTITY PER T/R	MINIMUM ORDER QUANTITY	PACKAGING DESCRIPTION					
VS-10ETF12SLHM3	800	800	13" diameter reel					

LINKS TO RELATED DOCUMENTS					
Dimensions <u>www.vishay.com/doc?95046</u>					
Part marking information	www.vishay.com/doc?95444				
Packaging information	www.vishay.com/doc?96317				



D²PAK

DIMENSIONS in millimeters and inches



CVMBOL	SYMBOL MILLIMETERS		MILLIMETERS INCHES		NOTES	SYMBOL	MILLIM	ETERS	INC	HES	NOTES	
STIVIBUL	MIN.	MAX.	MIN.	MAX.	NOTES		STIVIBUL	MIN.	MAX.	MIN.	MAX.	NOTES
Α	4.06	4.83	0.160	0.190			D1	6.86	8.00	0.270	0.315	3
A1	0.00	0.254	0.000	0.010			Е	9.65	10.67	0.380	0.420	2, 3
b	0.51	0.99	0.020	0.039			E1	7.90	8.80	0.311	0.346	3
b1	0.51	0.89	0.020	0.035	4		е	2.54	BSC	0.100	BSC	
b2	1.14	1.78	0.045	0.070			Н	14.61	15.88	0.575	0.625	
b3	1.14	1.73	0.045	0.068	4		L	1.78	2.79	0.070	0.110	
С	0.38	0.74	0.015	0.029			L1	-	1.65	-	0.066	3
c1	0.38	0.58	0.015	0.023	4		L2	1.27	1.78	0.050	0.070	
c2	1.14	1.65	0.045	0.065			L3	0.25	BSC	0.010	BSC	
D	8.51	9.65	0.335	0.380	2		L4	4.78	5.28	0.188	0.208	

Notes

- (1) Dimensioning and tolerancing per ASME Y14.5 M-1994
- (2) Dimension D and E do not include mold flash. Mold flash shall not exceed 0.127 mm (0.005") per side. These dimensions are measured at the outmost extremes of the plastic body
- (3) Thermal pad contour optional within dimension E, L1, D1 and E1
- (4) Dimension b1 and c1 apply to base metal only
- (5) Datum A and B to be determined at datum plane H
- (6) Controlling dimension: inch
- (7) Outline conforms to JEDEC® outline TO-263AB



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